

Proton and Neutron Irradiation Tests of Readout Electronics of the ATLAS Hadronic Endcap Calorimeter

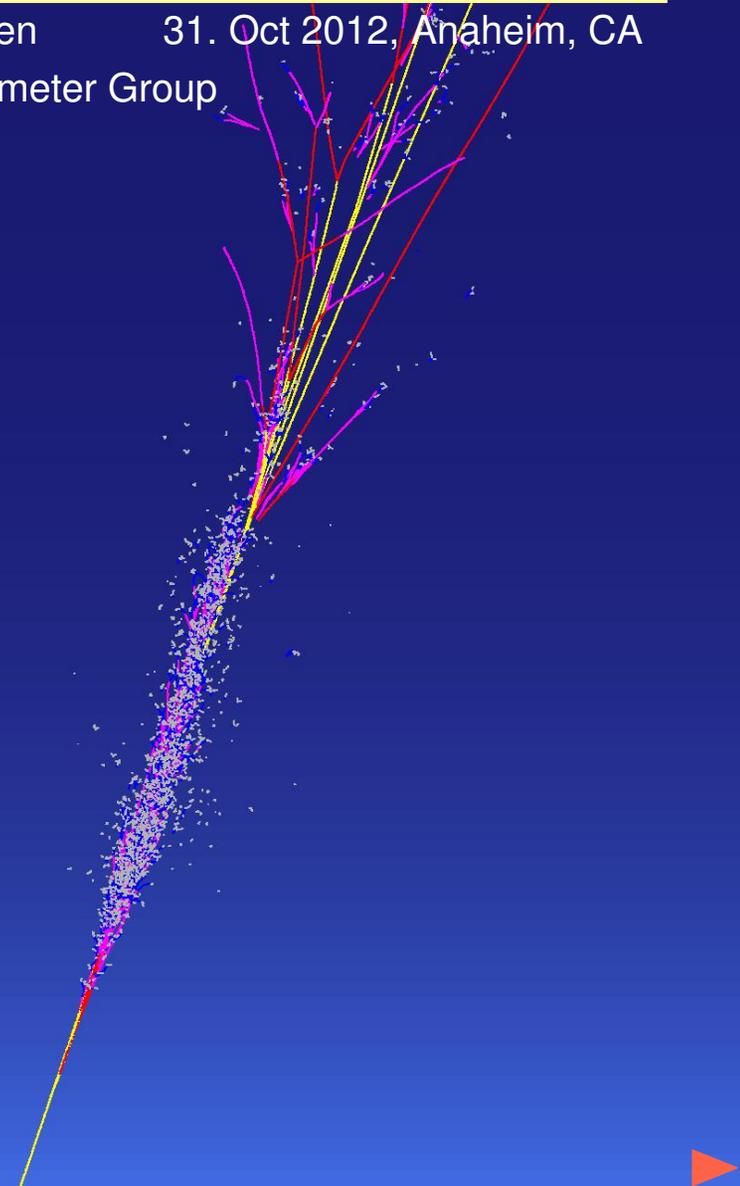
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Sven Menke, MPP München

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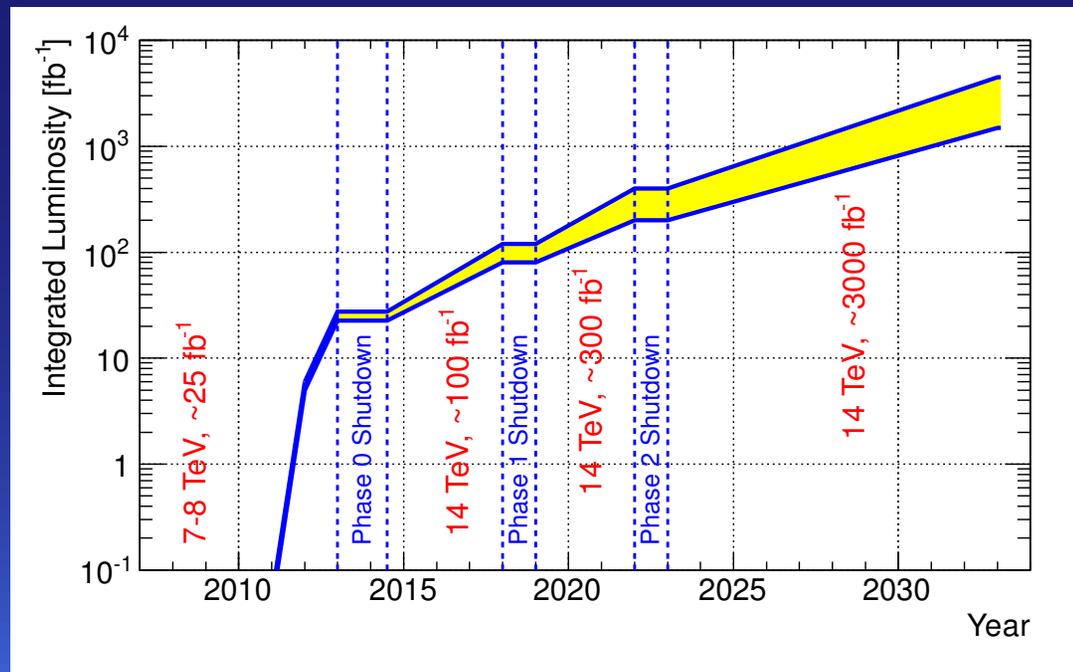
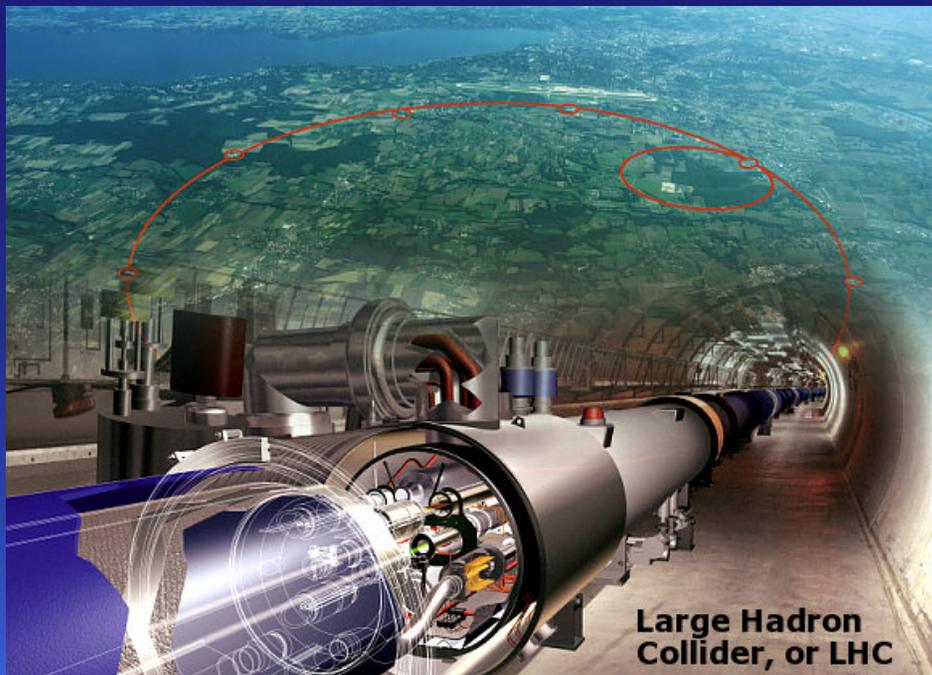
on behalf of the ATLAS Liquid Argon Calorimeter Group

- ▶ Introduction
- ▶ Proton irradiation at PSI
- ▶ Neutron irradiation in Řež
- ▶ Warm in-situ measurements
- ▶ Cold measurements after irradiation
- ▶ Conclusions

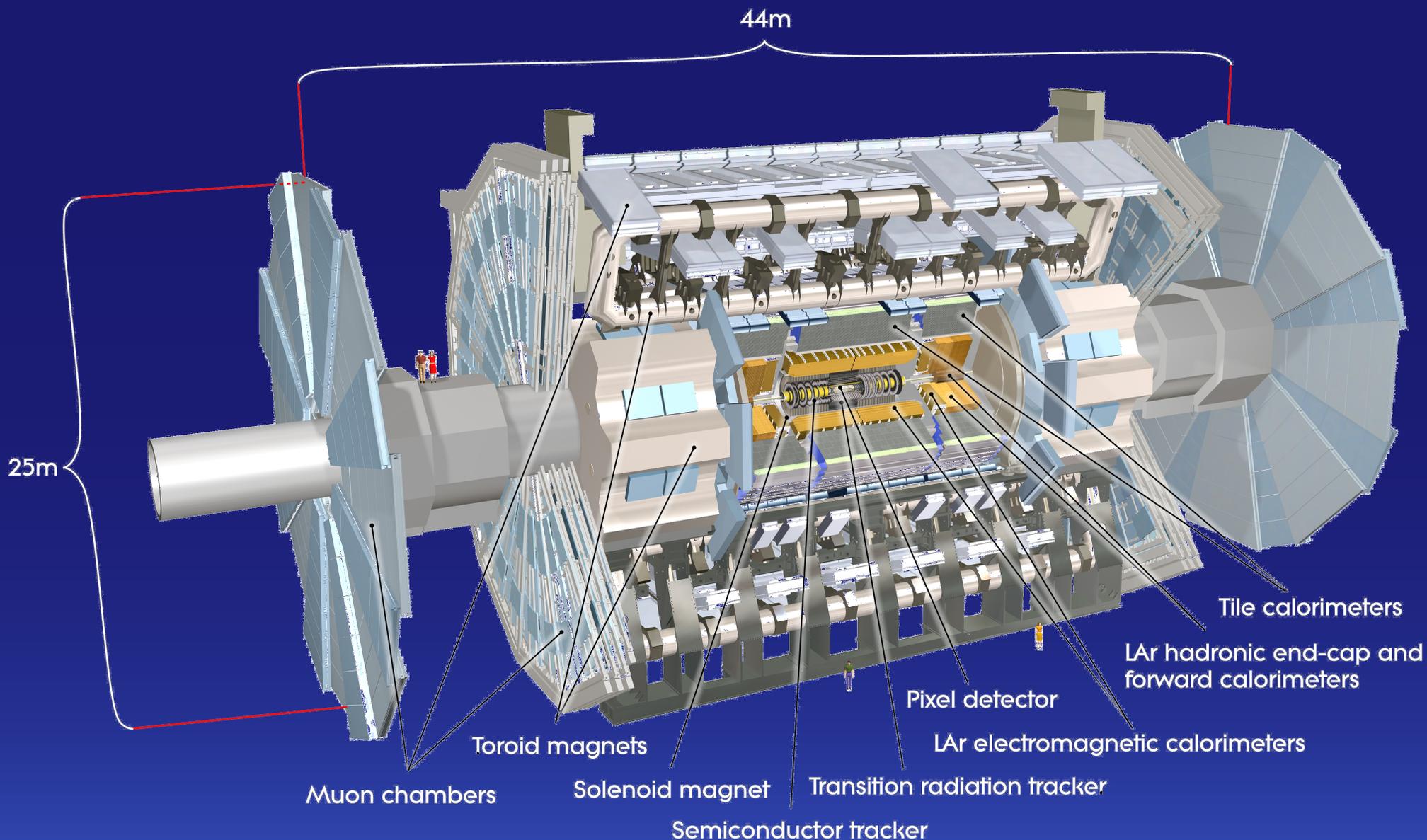


ATLAS and the HL-LHC

- ▶ LHC: pp collisions at $\sqrt{s} = 7 \text{ TeV}$ 2010 - 2011 and at $\sqrt{s} = 8 \text{ TeV}$ since March 2012
- ▶ several upgrade phases (energy and luminosity) are foreseen until 2023:
 - ▶ end of 2012: $\sim 25 \text{ fb}^{-1}$ pp collisions at 7-8 TeV
 - ▶ Phase 0 (until 2019): $\sim 100 \text{ fb}^{-1}$ pp collisions at 14 TeV
 - ▶ Phase 1 (until 2022): $\sim 300 \text{ fb}^{-1}$ pp collisions at 14 TeV
 - ▶ Phase 2 (beyond 2023): $\sim 3000 \text{ fb}^{-1}$ pp collisions at 14 TeV



The ATLAS Detector



A Torodial LHC ApparatuS: 25 m high; 44 m long; 7000 t heavy

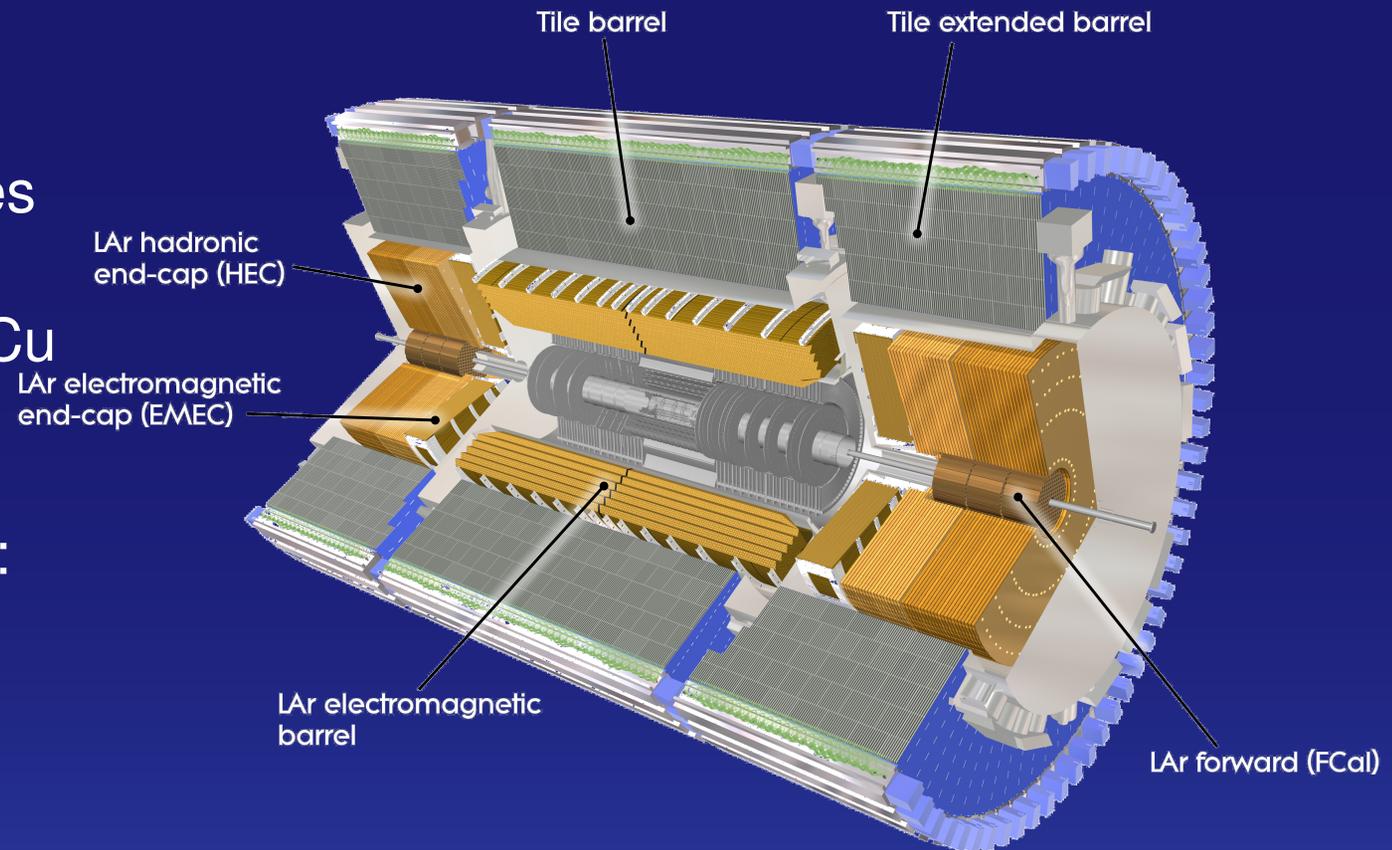
The ATLAS Detector ► Calorimetry

- Calorimeter coverage up to $|\eta| < 4.9$
- EM Barrel/Endcap: LAr/Pb Accordion $|\eta| < 1.4/1.375 < |\eta| < 3.2$

- Had Barrel:
iron/scintillating tiles
 $|\eta| \lesssim 1.7$

- Had Endcap: LAr/Cu
parallel plates
 $1.7 \lesssim |\eta| \lesssim 3.2$

- EM(HAD) Forward:
LAr/Cu(W) tubular
electrodes
 $3.2 \lesssim |\eta| \lesssim 4.9$

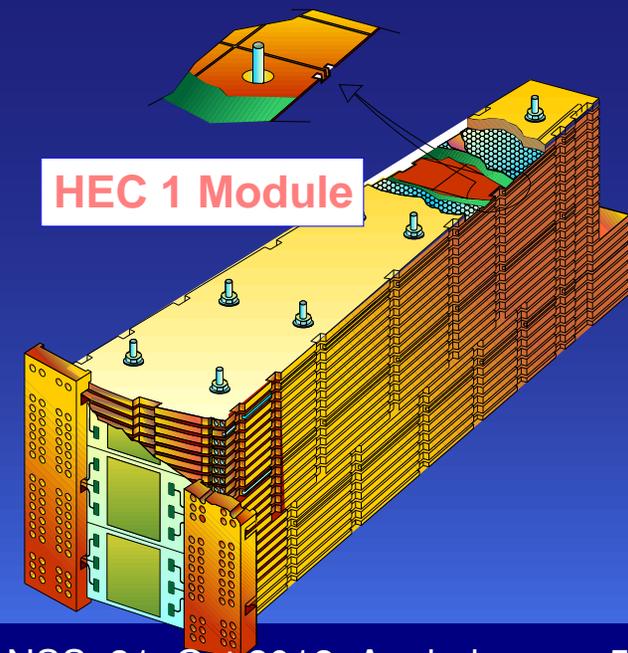


- typical cell sizes $\Delta\eta \times \Delta\phi = 0.025 \times 0.025$ (EM) and 0.1×0.1 (HAD);
3 to 7 samplings; at least $24 X_0$ (EM) and 10λ (EM+HAD)
- e/γ : $\sigma_E/E \simeq 10\%/\sqrt{E}$
- jets: $\sigma_E/E \simeq 50\%/\sqrt{E} \oplus 3\%$

The Hadronic Endcap Calorimeter of ATLAS (HEC)

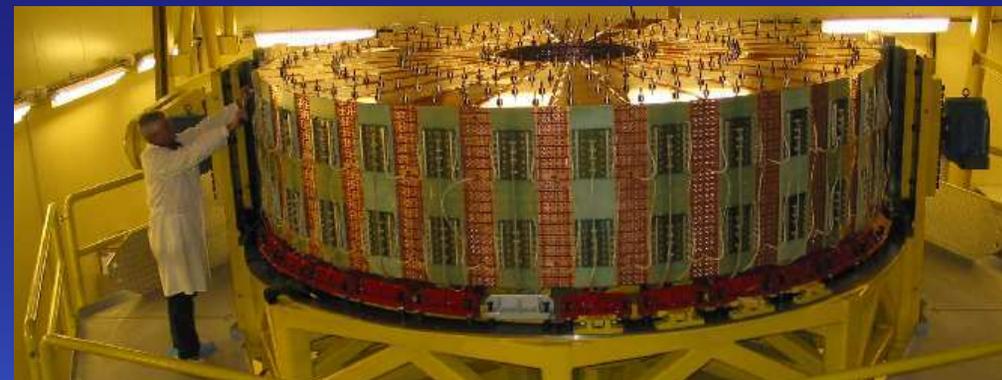
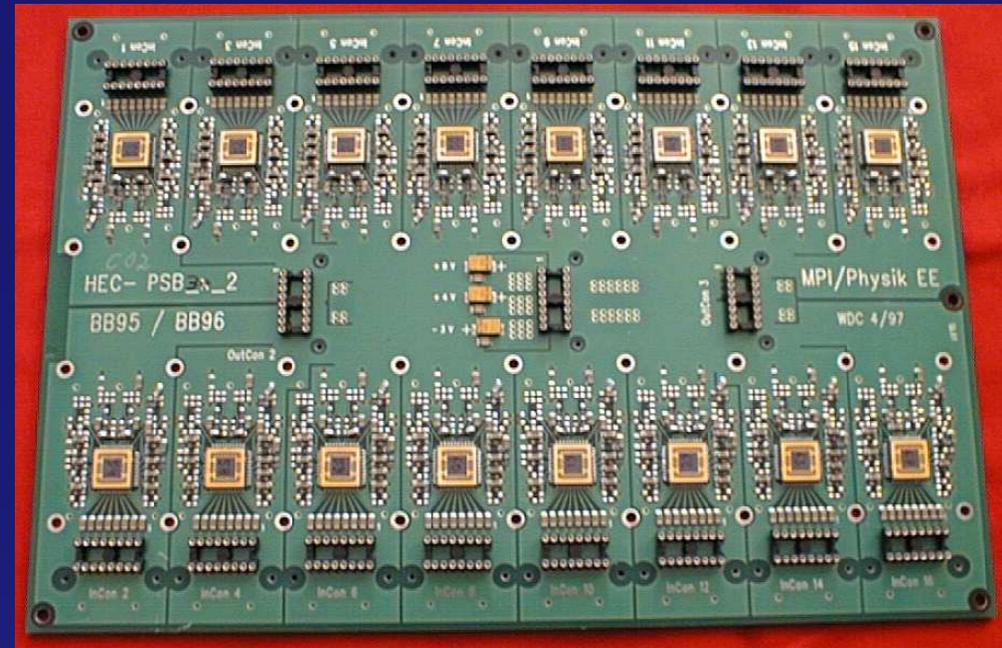
- ▶ The Hadronic Endcap Calorimeter of ATLAS consists of 2 calorimeters (one per endcap) and each of those of 2 wheels (front and back)
- ▶ It's a sampling calorimeter with copper plates as absorbers and liquid argon as sensitive material
- ▶ The wheels are segmented in φ into 32 modules and in z in 4 layers
- ▶ Each module has for each layer one or two Preamplifier and Summing Boards (PSB) attached directly on the outer perimeter – i.e. the electronics sits inside the liquid argon cryostat and is exposed to severe radiation

- ▶ HEC absorber structure
 - Absorbers plates parallel to beam axis
 - 2.5 cm thick Cu plates in HEC 1
 - 5.0 cm thick Cu plates in HEC 2



HEC Cold Electronics

- ▶ The heart of the PSBs are ~ 2600 GaAs ASICs with 8 input channels and 2 output channels
- ▶ Design principles for the ASICs:
 - 2 stage design consisting of 8 Pre-Amplifiers (PA) and 2 summing-amplifiers or drivers
 - large PA input transistor for low noise
 - input impedance of 50Ω and large output impedance to allow summing of signals after the PAs
 - good high-frequency performance (up to ~ 20 MHz)
 - adjustable gain and timing by external components
 - radiation hardness for (Safety Factor = 10) \times 12 years of LHC running
 - low power consumption to avoid LAr boiling
- ▶ upper picture shows one PSB
- ▶ lower picture shows one HEC wheel with PSBs mounted on the outer perimeter

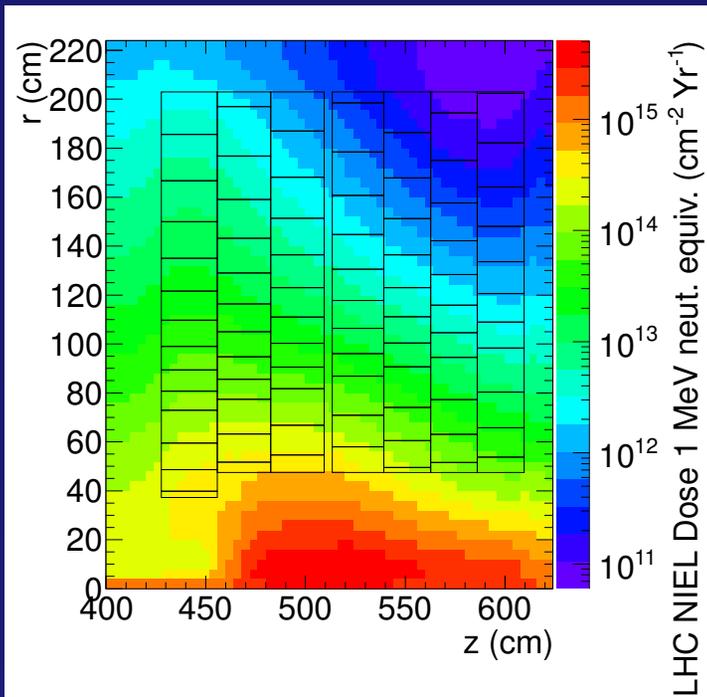


Radiation Levels in ATLAS

▶ look at simulations of neutrons (NIEL), hadrons ($E > 20$ MeV), and total ionization dose (TID) for ATLAS from 2003

▶ the numbers correspond to

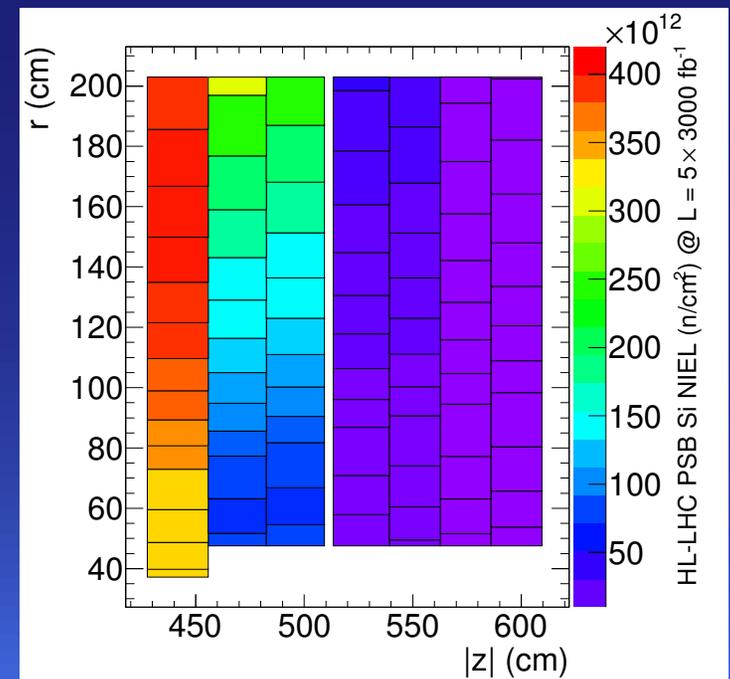
- 14 TeV pp collisions with $\sigma_{\text{inel}} = 79.3$ mb
- Nominal luminosity of $\mathcal{L} = 10^{34} \text{ cm}^{-2} \text{ s}^{-1}$
- A standard running year of 10^7 s or 100 fb^{-1} per year
- plot to the left shows NIEL for 1 LHC year in the HEC region



▶ ASICs are located at $r = 204$ cm and $429 \text{ cm} < |z| < 597$ cm

▶ assumptions for HL-LHC:

- 14 TeV pp collisions with $\sigma_{\text{inel}} = 79.3$ mb
- Nominal (average) luminosity of $\mathcal{L} = 3 \times 10^{34} \text{ cm}^{-2} \text{ s}^{-1}$
- A standard running year of 10^7 s or 300 fb^{-1} per year
- A running time of 10 years
- A safety factor of 5 for the simulation
- plot to the right shows NIEL dose in PSBs at the location of the corresponding calorimeter segment

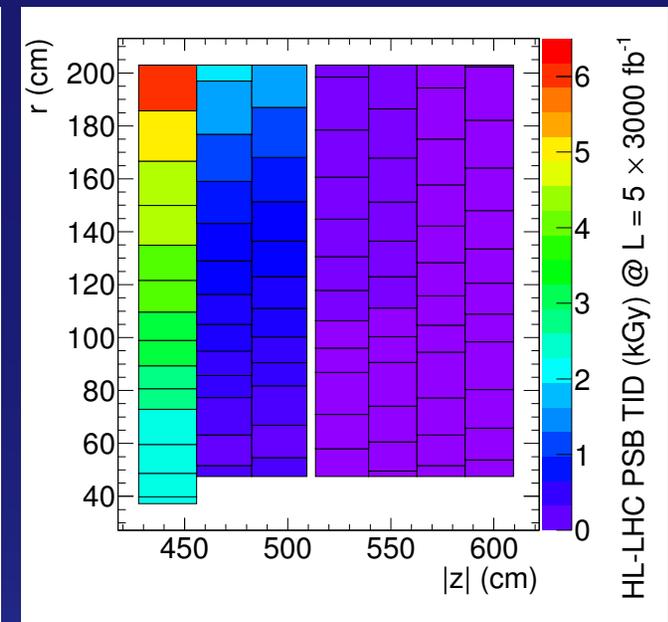
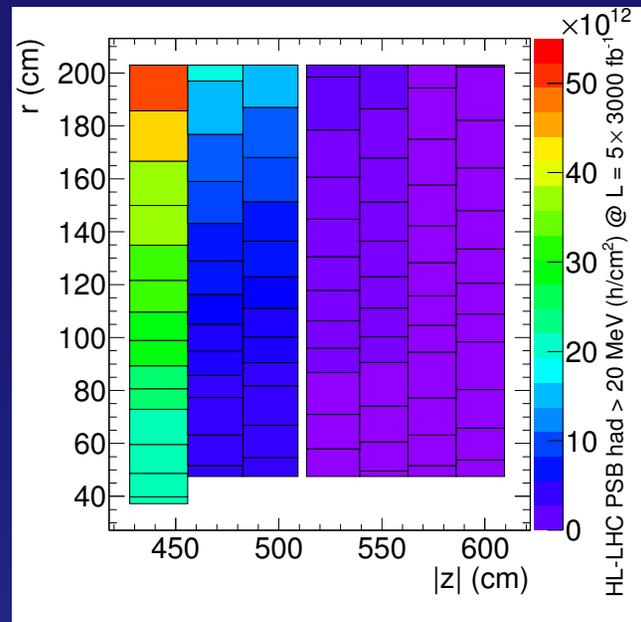


Radiation Levels in ATLAS

- ▶ similar plots below for the HL-LHC expected values at the ASIC locations (plotted at the corresponding HEC cell) for hadrons ($E > 20$ MeV), and total ionization dose (TID)

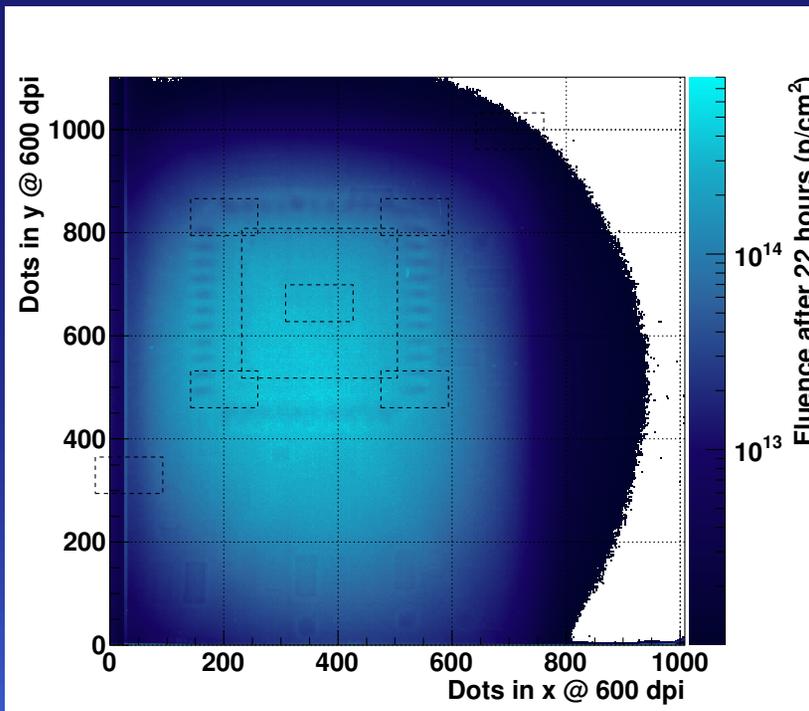
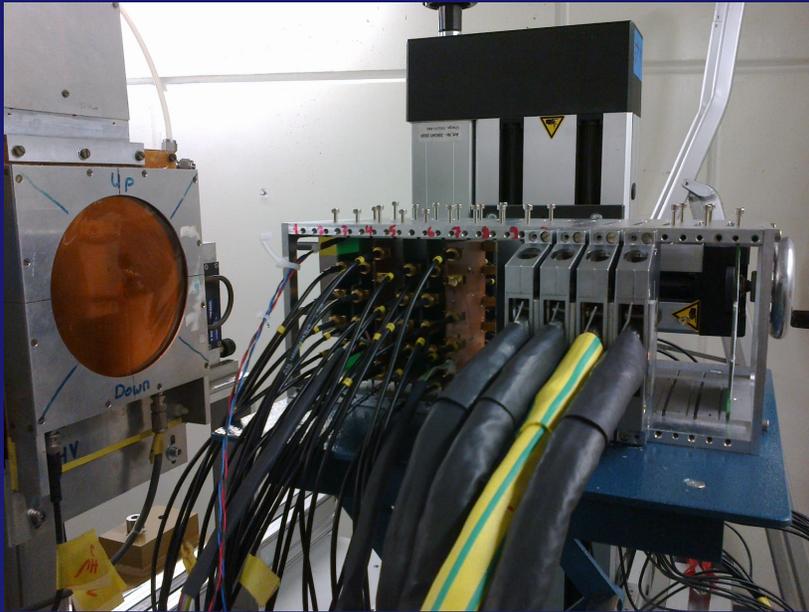
- ▶ the limiting numbers for all are reached in the first and most important section of the HEC at the lowest $|\eta|$ values

- ▶ NIEL: 4.1×10^{14} n/cm²
- ▶ hadrons ($E > 20$ MeV): 5.1×10^{13} h/cm²
- ▶ TID: 6.2 kGy



- ▶ use 200 MeV protons from the Proton Irradiation Facility (PIF) at the PSI to test hadrons $E > 20$ MeV
- ▶ use neutrons from (p, n) reaction of 36 MeV protons on D₂O target at Řež to test NIEL

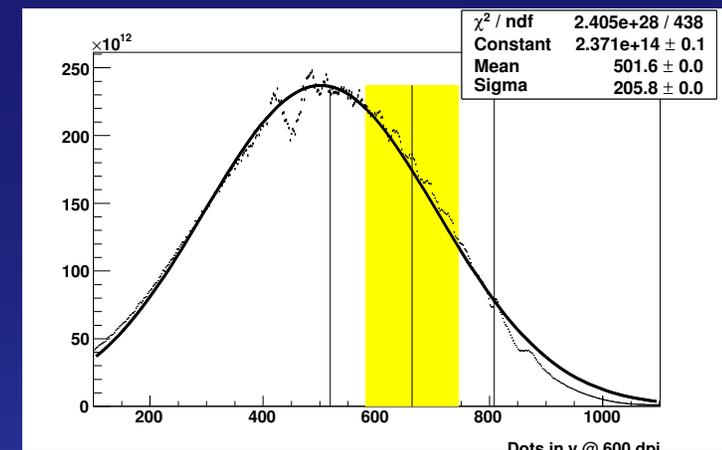
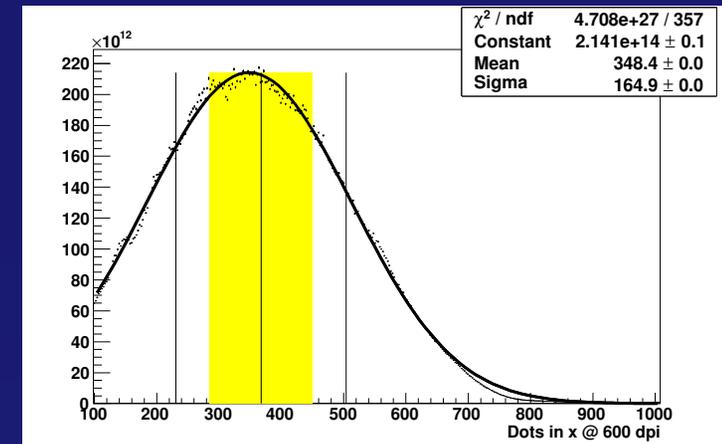
Proton Test May 2011@PSI



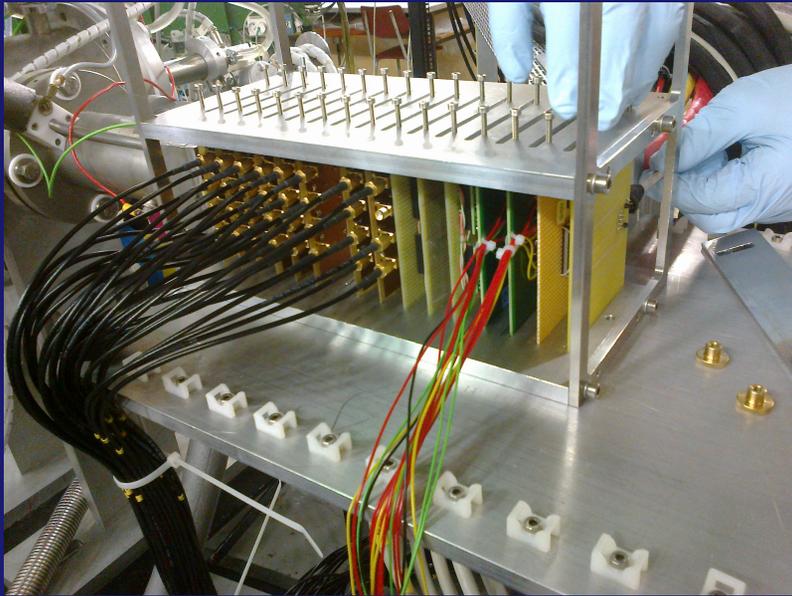
- ▶ proton beam from cyclotron with 198.9 MeV and ~ 2.7 nA for ~ 22 h and $\sim 7 \times 8.5$ mm² width (6.5 mm offset in y)
- ▶ beam comes from the left
- ▶ aluminum frame with up to 16 slots and 17 mm spacing
- ▶ final alignment was done closer to the collimator (5 cm)
- ▶ Slots 3 and 6 present HEC ASICs (BB96)
- ▶ For 5 minutes radiation films in Slots 2-6, 10 (not on picture)

Proton Fluence May 2011 at PSI

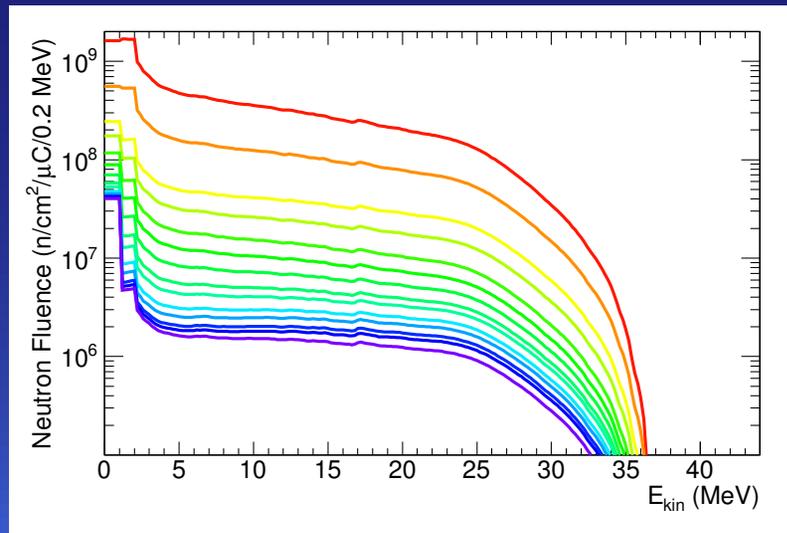
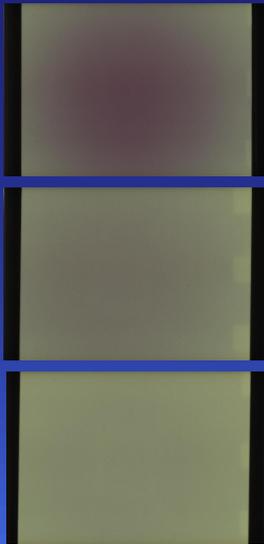
- ▶ Proton Beam at PSI was normalized with Ionization Chamber (IC) measurement: $255 \text{ nA} \equiv 3 \text{ nA}$ proton beam
- ▶ radiation films revealed displaced beam spot and confirmed small beam width:
 - ▶ $\Delta_x = (0 \pm 1) \text{ mm}$
 - ▶ $\Delta_y = (-6.5 \pm 0.1) \text{ mm}$
 - ▶ $\sigma_x = (7.1 \pm 0.2 - (0.08 \pm 0.03)\#_{\text{slot}}) \text{ mm}$
 - ▶ $\sigma_y = (8.5 \pm 0.2 + (0.11 \pm 0.03)\#_{\text{slot}}) \text{ mm}$
- ▶ The total fluence in the relevant areas of all slots is found to be constant and after 22.05 h of beam time at an average current of 2.714 nA is found to be $(2.6 \pm 0.4) \times 10^{14} \text{ p/cm}^2$
- ▶ The biggest contribution to the 15% error stems from the displaced beam spot in y which causes a large variation of the total intensity (12% for $\pm 2.5 \text{ mm}$)



Neutron Test February 2012@Řež



- ▶ neutron irradiation at the 36 MeV proton cyclotron in Řež from 17.2.-19.2.2012
- ▶ beam comes from the left and enters D₂O target to produce neutrons
- ▶ similar aluminum frame with 16 slots and 17 mm spacing as at PSI
 - in slots 1-6,8,9: BB96 (the HEC chip) with 4 channels (3 for slot 9) each
 - in front of slot 1: radiation films at $\sim 1.2 \mu\text{A}$ for 60, 120, and 300 s.
 - behind slots 2-6,8,9,12-15: films in the 300 s $1.2 \mu\text{A}$ run



Neutron Fluence

- ▶ compare relative dose of films to results from 2010 run with radmons in each slot and account for additional 3 mm distance

- ▶ total fluence per slot for $2.0 \times 10^6 \mu\text{C}$:

$$\text{fluence} = 3.22 \times 10^{16} \times \left(\text{slot} + \frac{3}{17}\right)^{-2.11} \frac{\text{n}}{\text{cm}^2}$$

- ▶ estimated error from distance uncertainty $\pm 2 \text{ mm}$

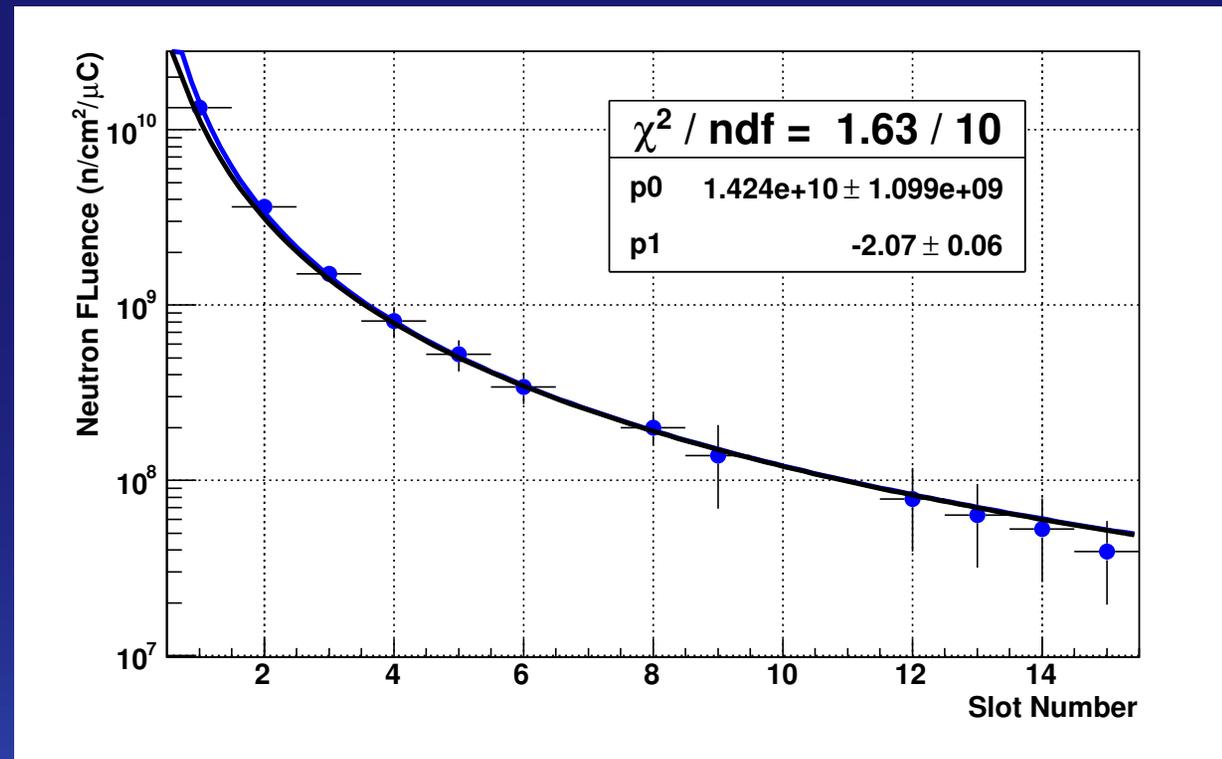
- ▶ $\sim 25\%$ in slot 1

- ▶ $\sim 3\%$ in slot 8

- ▶ estimated error from current measurement $\pm 5\%$

- ▶ total $\sim 25\%$ in slot 1

- ▶ total $\sim 6\%$ in slot 8

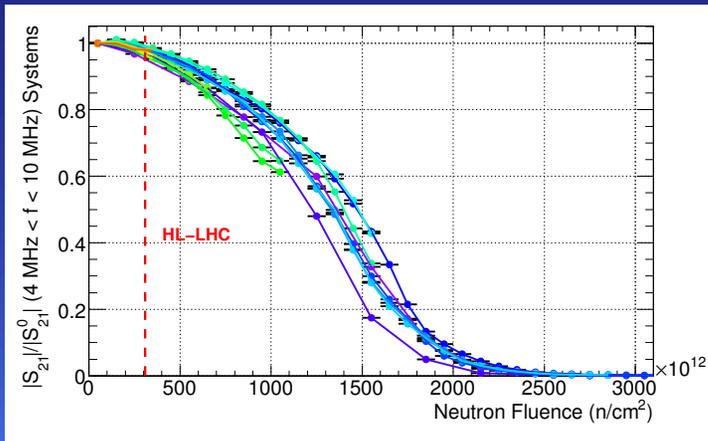
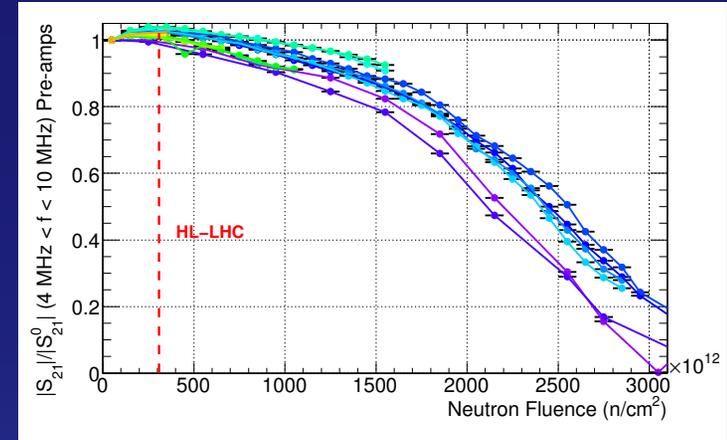
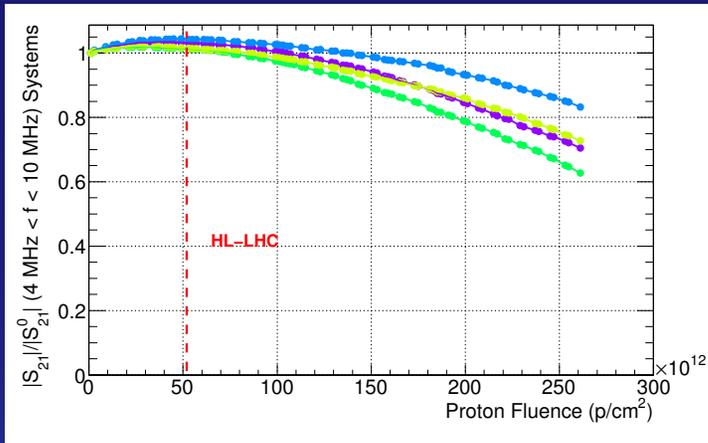
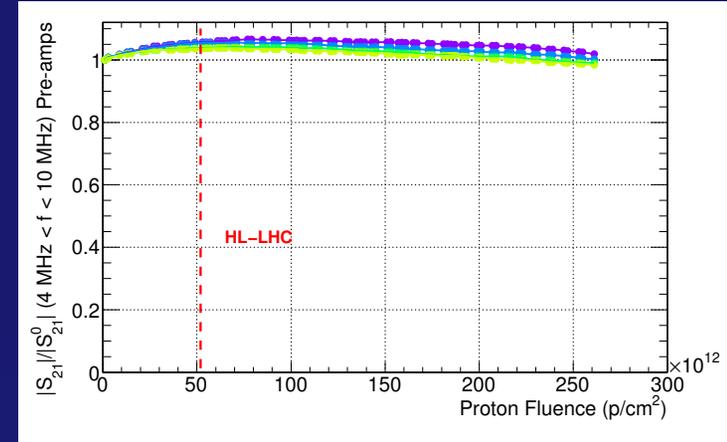


Measurements

- ▶ Warm in-situ measurements for the HEC Chips:
 - Monitoring of DC values
 - Calibrated S-parameters over 2×40 m cables in the frequency range 300 kHz to 100 MHz at -55 dBm (-35 dBm at PSI) cable input level
 - Oscilloscope linearity scan with 500 ns triangular voltage pulses corresponding to $10 \mu\text{A} - 1000 \mu\text{A}$ at BB96 input for 10 logarithmically distributed points (Řež only)
- ▶ Cold measurements of the n-irradiated HEC Chips:
 - about 3 months after the neutron irradiation the boards were shippable
 - we re-measured the S-parameters and pulse response in the Lab under cold (LN_2) conditions
 - in a small cryostat ($\sim 3 \ell$) with 2 boards at a time
 - We measure continuously like in Řež all S-parameters, DC values and pulse response and temperature

Proton and Neutron in-situ Measurements (Warm)

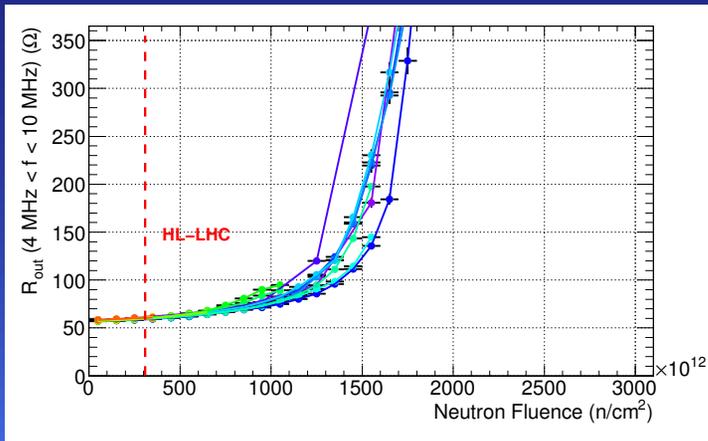
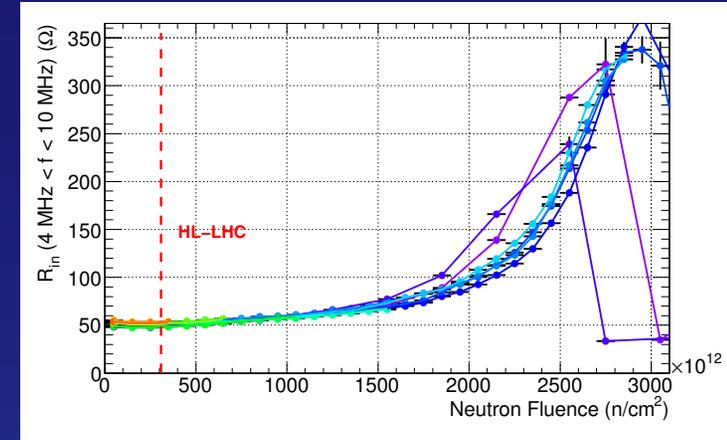
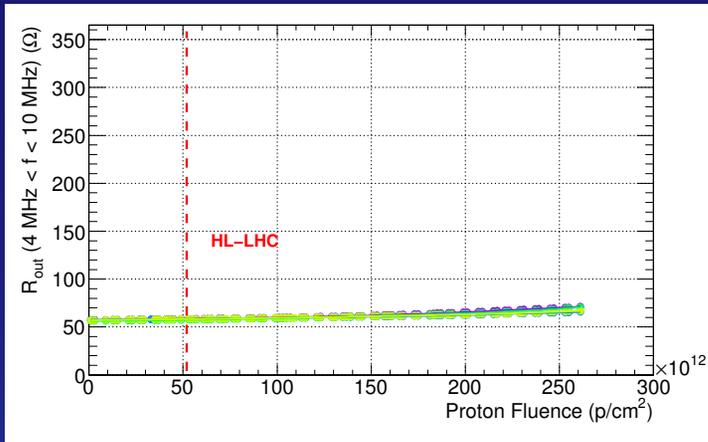
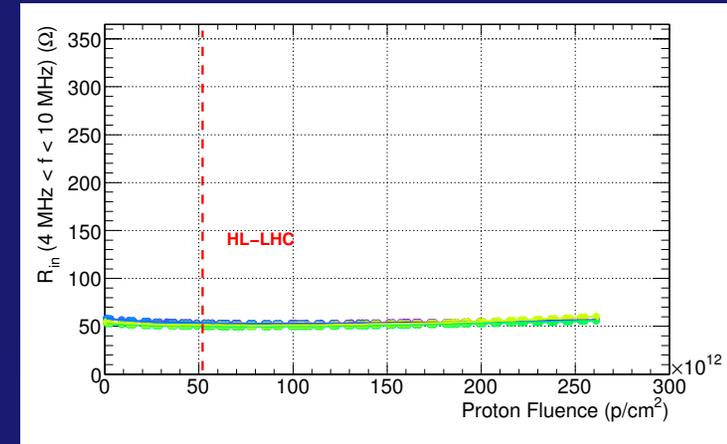
- ▶ evaluate gain of pre-amps (right) at frequencies relevant for shaper ($4 \text{ MHz} < f < 10 \text{ MHz}$)
- ▶ normalize to values before irradiation
- ▶ for protons (top) and neutrons (bottom)



- ▶ and for the systems (left)
- ▶ protons have $\sim 4 - 5 \times$ larger effect at the same fluence value
 - ▶ but neutron rates are $\sim 10 \times$ that of hadrons ($E > 20 \text{ MeV}$)
- ▶ red dashed lines indicate HL-LHC levels (adjusted for GaAs NIEL in case of neutrons)

Proton and Neutron in-situ Measurements (Warm)

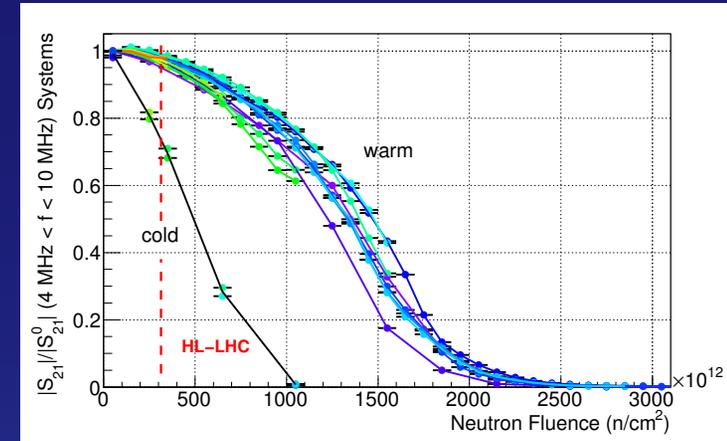
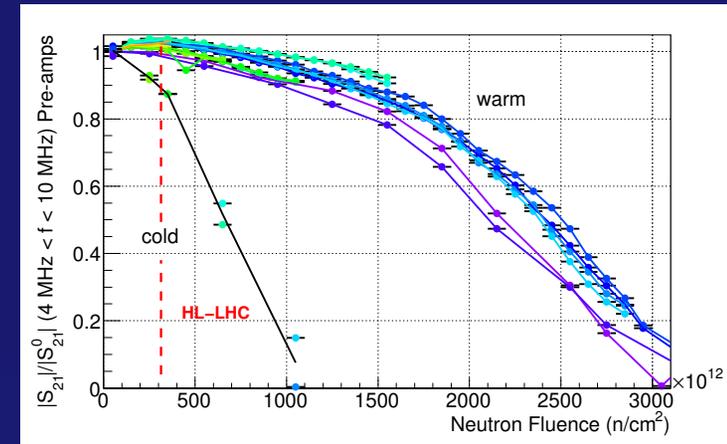
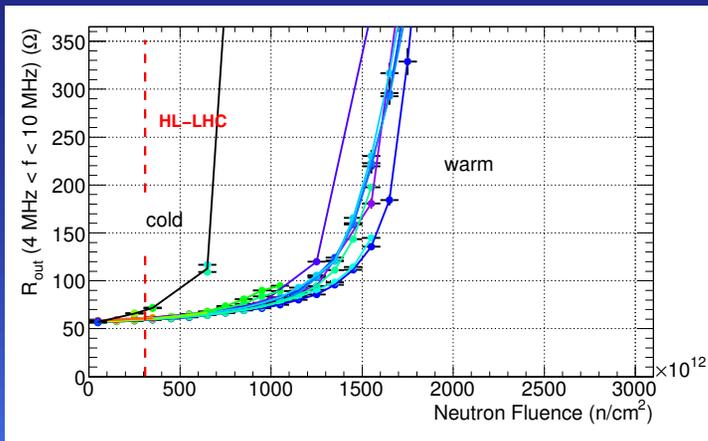
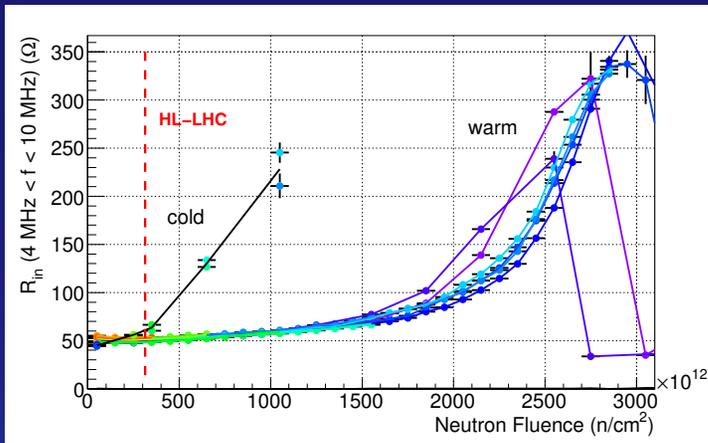
- ▶ input impedance for the pre-amps (right) at frequencies relevant for shaper ($4 \text{ MHz} < f < 10 \text{ MHz}$)
- ▶ for protons (top) and neutrons (bottom)



- ▶ and output impedance for the systems (left)
- ▶ for protons (top) and neutrons (bottom)
- ▶ R_{out} rises quickly beyond $\sim 10^{15} \text{ n/cm}^2$

Gain and Impedances in Warm and Cold

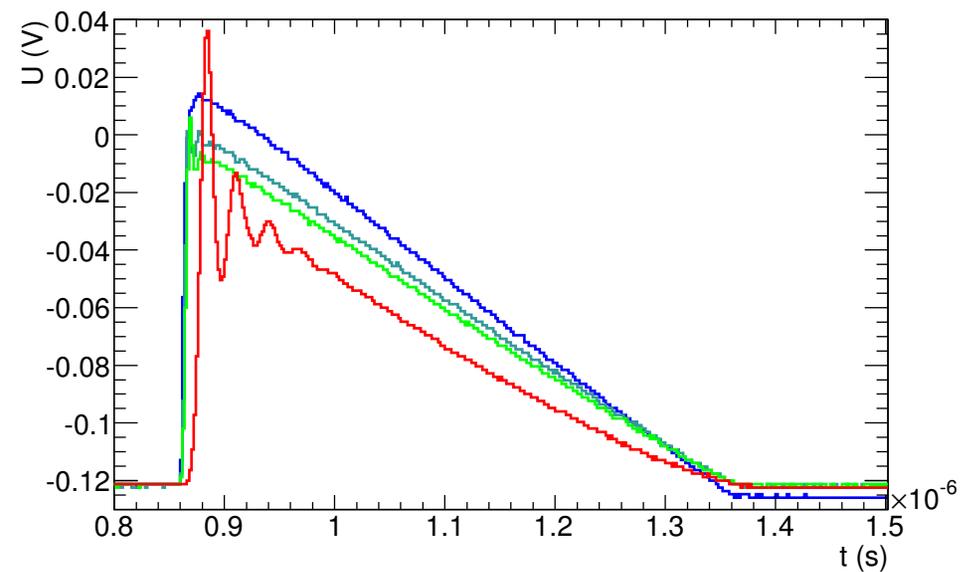
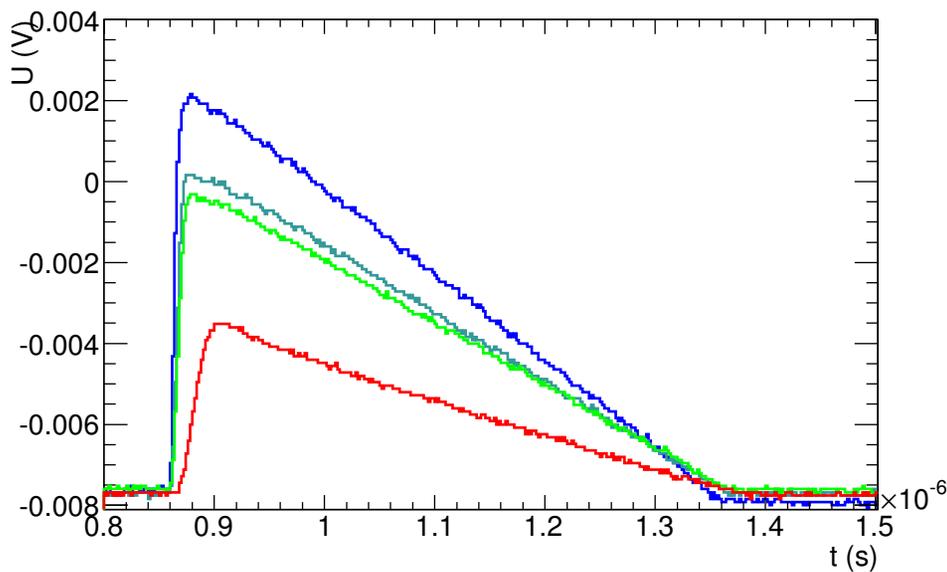
- ▶ evaluate gain at frequencies relevant for shaper ($4 \text{ MHz} < f < 10 \text{ MHz}$)
- ▶ normalize to values before irradiation
- ▶ right top (bottom) plot shows pre-amps (systems)



- ▶ in cold the gain of the pre-amps is much worse after irradiation
- ▶ also the input (left top) and output (left bottom) impedances rise quickly
- ▶ non-matched circuits

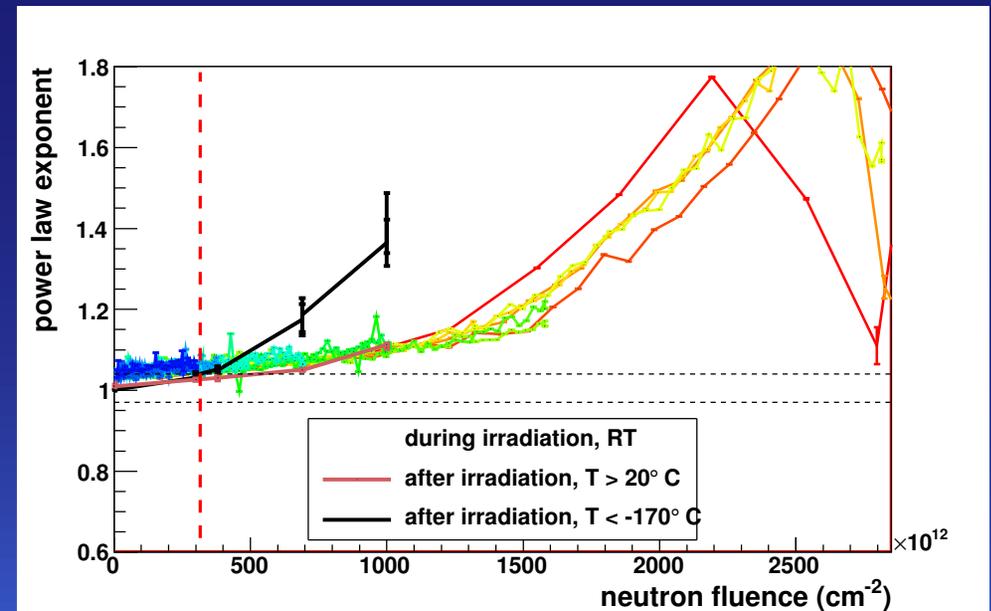
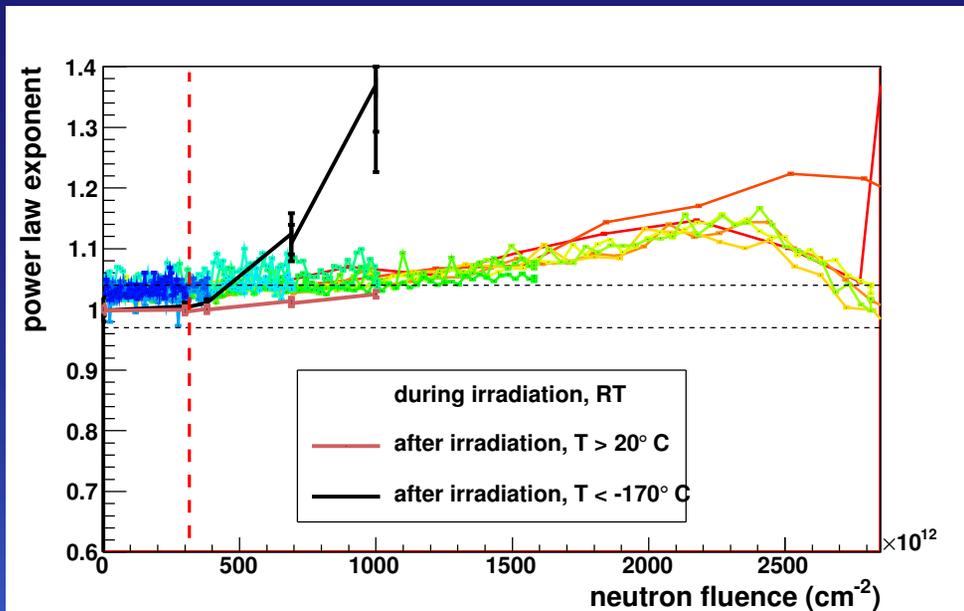
Cold Oscilloscope Measurements

- ▶ blue: non-irradiated
- ▶ cyan: slot 9 (Si NIEL = 3.0×10^{14} n/cm²)
- ▶ green: slot 8 (Si NIEL = 3.8×10^{14} n/cm²)
- ▶ red: slot 6 (Si NIEL = 6.9×10^{14} n/cm²)
- ▶ left a small input pulse; right a $13.5\times$ larger input pulse
- ▶ relative to the blue pulse the other pulses should have the same height on the left and the right for a linear system
- ▶ non-linearities and oscillations are getting severe already for the green pulses ...



Comparison of warm and cold non-linearities

- ▶ Shown are the exponents of a power-law-fit of the form $out = a \times in^x$
- ▶ as measured in Řež (warm) in-situ as many colored points/lines
- ▶ re-measured for 4 irradiated boards at MPI (warm) in brown
- ▶ re-measured for same 4 irradiated boards at MPI (cold) in black
- ▶ horizontal lines indicate $\Delta_{max} = 1\%$ limits, where Δ_{max} is the deviation from a linear fit ($x = 1$) relative to the maximum output
- ▶ non-irradiated BB96 are better in the cold
- ▶ severe increase of non-linearity ~ 3 times earlier in cold than in warm



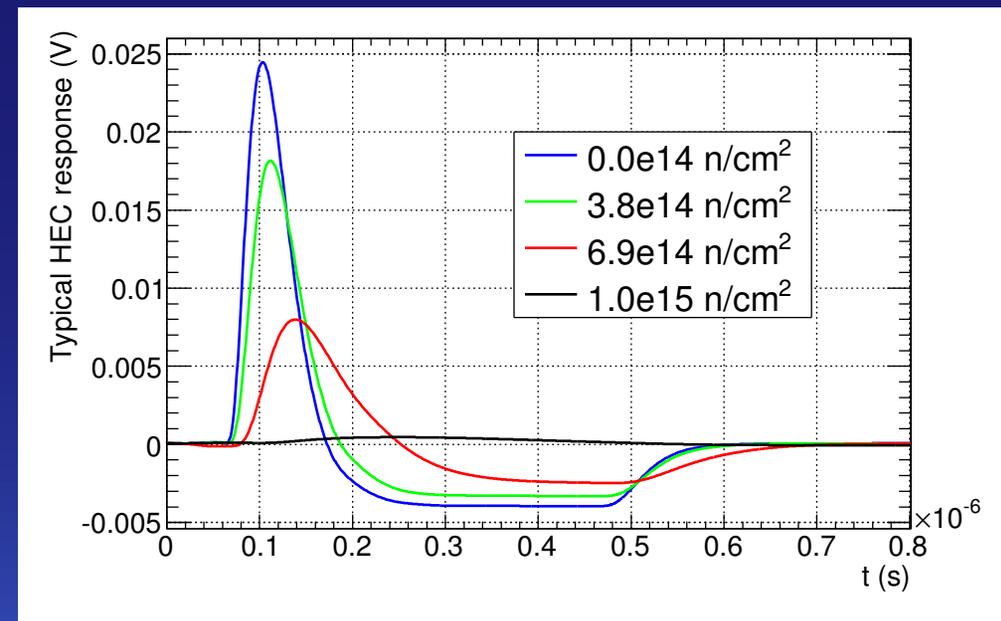
Summary of cold measurements

► Cold measurements show:

- BB96 rapidly degrades beyond $3 - 4 \times 10^{14} \text{ n/cm}^2$ Si-NIEL (Řež)
- input and output impedance not longer matching 50Ω system
- signals start to oscillate
- gain, bandwidth and dynamic range get limited
- pulses get broader

► This translates to $4.0 - 5.4 \times 10^{14} \text{ n/cm}^2$ Si-NIEL (ATLAS) (see Appendix)

- non-linearities (in the Δ_{max} -sense) rise above 3%
- simulations of the full electronics readout chain with all measured S-parameters (right) show that the degradation in $|S_{21}|$ describes the degradation in transimpedance gain



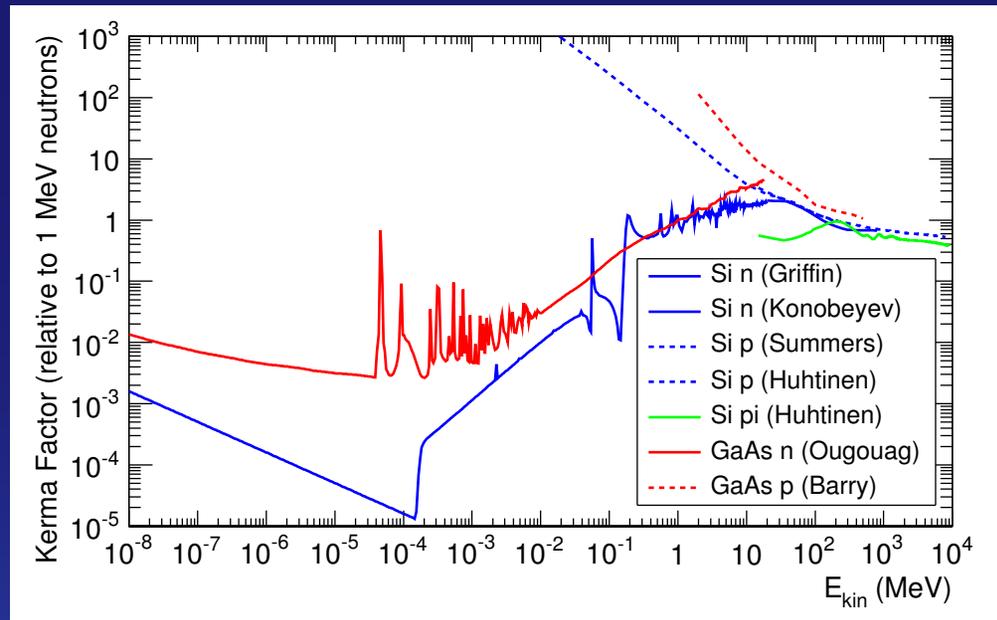
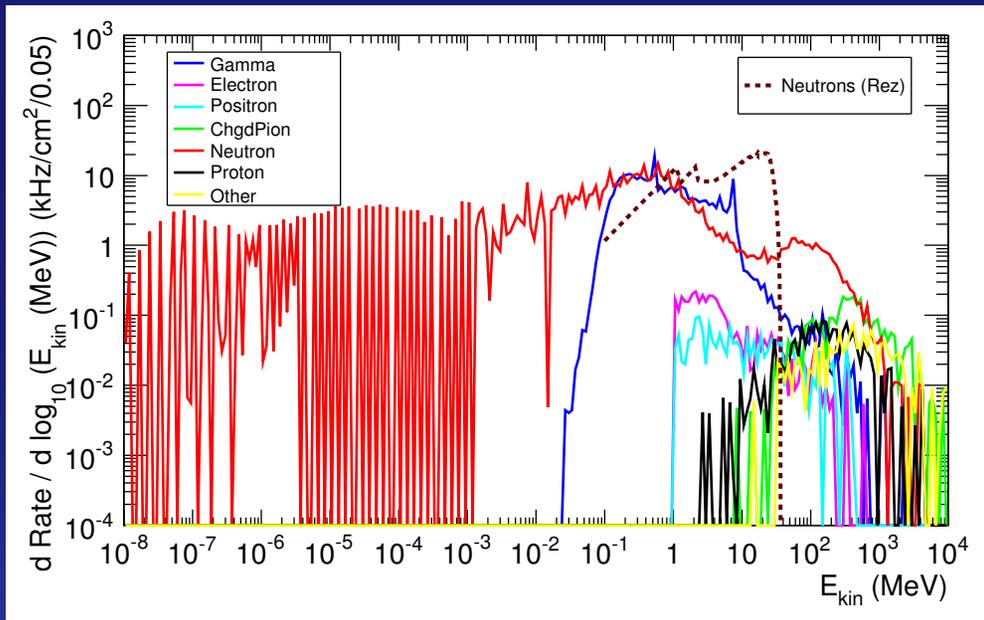
- the rising input impedance does not compensate the voltage gain loss

Conclusions

- ▶ How to combine the proton and neutron results?
 - proton irradiated chips measured only in warm
 - compared to the neutron measurements in warm the protons produced a 4 – 5 times larger damage at the same fluence values
 - translate the proton flux to non-ionizing dose (NIEL) plus ionizing dose (TID) and assume similar effects for cold vs. warm
 - ▶ we expect additional TID degradation on the level of $\sim 10\%$ of the NIEL degradation
- ▶ NIEL measurements from neutrons set the most stringent limits on the present readout electronics of HEC
- ▶ the values expected for HL-LHC including simulation safety factors of 5 are at the working limit for the BB96 ASICs
- ▶ the impact on physics analyses at HL-LHC with degraded electronics is under investigation

Appendix: NIEL Calculations

- ▶ to compare Si-NIEL for GaAs devices one has to convert to GaAs NIEL at one site (test facility) and back to Si NIEL at the other site (ATLAS)
- ▶ this requires the knowledge of the particle spectra
- ▶ For Řež we have a MCNP based simulation
 - ▶ the Řež ratio GaAs NIEL/Si NIEL is ~ 1.82
- ▶ The spectra for ATLAS are taken from FLUKA simulations in the HEC PSB region
 - ▶ for ATLAS in the HEC PSB region the ratio GaAs NIEL/Si NIEL is ~ 1.35



- ▶ Thus to translate from Řež to ATLAS it is best to stick to Si-Numbers and multiply by 1.82/1.35
- ▶ 3.8×10^{14} n/cm² Si-NIEL in Řež corresponds to 5.1×10^{14} n/cm² Si-NIEL in ATLAS for GaAs devices in the PSB HEC region